

TSMF3700

Vishay Semiconductors

High Speed Infrared Emitting Diode, 870 nm, GaAIAs Double Hetero

Description

TSMF3700 is a high speed infrared emitting diode in GaAlAs on GaAlAs double hetero (DH) technology in a miniature PL-CC-2 SMD package.

It has been designed to meet the increasing demand on optoelectronic devices for surface mounting.

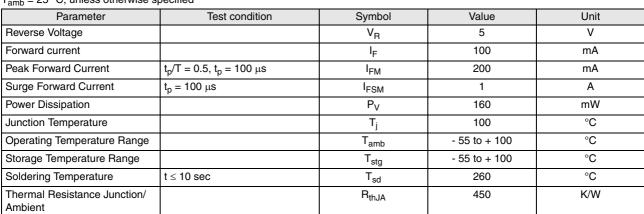
The package consists of a lead frame which is surrounded with a white thermoplast. The reflector inside the package is filled up with clear epoxy.

Features

- SMT IRED with extra high radiant power
- · Low forward voltage
- · Compatible with automatic placement equipment
- EIA and ICE standard package
- · Suitable for infrared, vapor phase and wavesolder process
- Available in 8 mm tape
- Suitable for pulse current operation
- Extra wide angle of half intensity $\phi = \pm 60^{\circ}$
- Peak wavelength $\lambda_p = 870 \text{ nm}$
- · High reliability
- Lead-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

Absolute Maximum Ratings

 $T_{amb} = 25 \ ^{\circ}C$, unless otherwise specified



Rev. 1.4, 08-Mar-05



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Applications

Infrared source in tactile keyboards IR diode in low space applications High performance PCB mounted infrared sensors High power infrared emitter for miniature light barriers

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Electrical Characteristics

 T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Forward Voltage	I _F = 100 mA, t _p = 20 ms	V _F		1.4	1.7	V
	$I_{F} = 1 \text{ A}, t_{p} = 100 \ \mu \text{s}$	V _F		2.4		V
Temp. Coefficient of V _F	I _F = 100 mA	TK _{VF}		- 1.7		mV/K
Reverse Current	V _R = 5 V	I _R			10	μA
Junction capacitance	V _R = 0 V, f = 1 MHz, E = 0	Cj		160		pF

Optical Characteristics

 T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min	Тур.	Мах	Unit
Radiant Intensity	I _F = 100 mA, t _p = 20 ms	Ι _e	5	7	25	mW/sr
	$I_{F} = 1 \text{ A}, t_{p} = 100 \ \mu \text{s}$	Ι _e		60		mW/sr
Radiant Power	I _F = 100 mA, t _p = 20 ms	φ _e		32		mW
Temp. Coefficient of ϕ_{e}	I _F = 100 mA	TKφ _e		- 0.8		%/K
Angle of Half Intensity		φ		± 60		deg
Peak Wavelength	I _F = 100 mA	λ _p		870		nm
Spectral Bandwidth	I _F = 100 mA	Δλ		40		nm
Temp. Coefficient of λ_p	I _F = 100 mA	TKλ _p		0.2		nm/K
Rise Time	I _F = 100 mA	t _r		30		ns
Fall Time	I _F = 100 mA	t _f		30		ns
Virtual Source Diameter		Ø		0.5		mm

Typical Characteristics (Tamb = 25 °C unless otherwise specified)

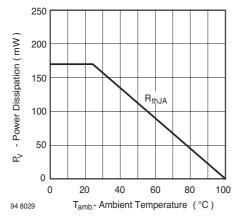


Figure 1. Power Dissipation vs. Ambient Temperature

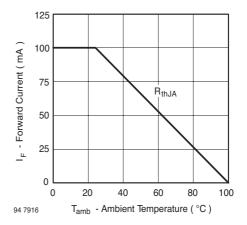


Figure 2. Forward Current vs. Ambient Temperature



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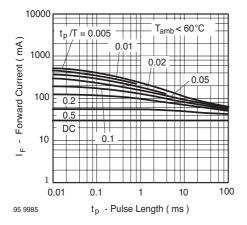


Figure 3. Pulse Forward Current vs. Pulse Duration

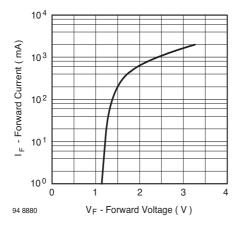


Figure 4. Forward Current vs. Forward Voltage

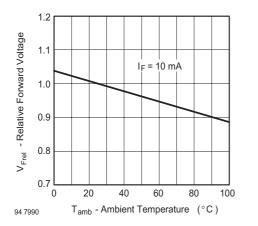


Figure 5. Relative Forward Voltage vs. Ambient Temperature

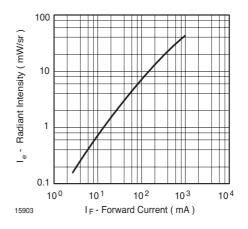


Figure 6. Radiant Intensity vs. Forward Current

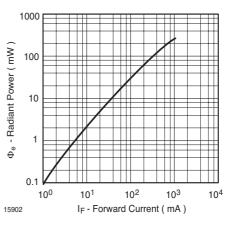


Figure 7. Radiant Power vs. Forward Current

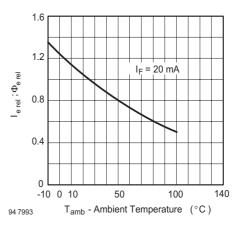
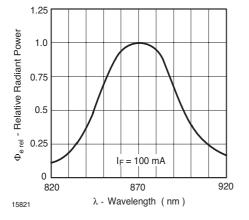


Figure 8. Rel. Radiant Intensity/Power vs. Ambient Temperature

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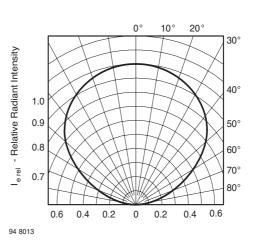
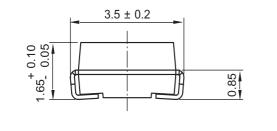
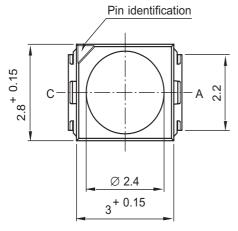


Figure 10. Relative Radiant Intensity vs. Angular Displacement

Package Dimensions in mm

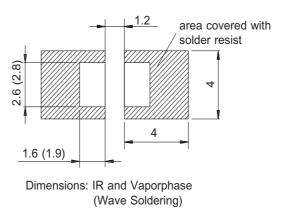






Drawing-No. : 6.541-5025.01-4 Issue: 7; 05.04.04

Mounting Pad Layout



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Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operatingsystems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

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